



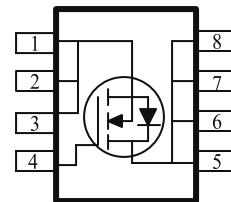
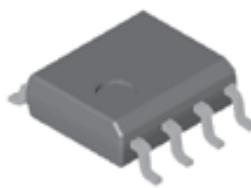
## N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low  $r_{DS(on)}$  provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology

### PRODUCT SUMMARY

$V_{DS}$ (V)	$r_{DS(on)}$ m( $\Omega$ )	$I_D$ (A)
30	13.5 @ $V_{GS} = 4.5V$	13
	20 @ $V_{GS} = 2.5V$	11



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current <sup>a</sup>	$I_D$	$\pm 13$	A
		$\pm 11$	
Pulsed Drain Current <sup>b</sup>	$I_{DM}$	$\pm 50$	
Continuous Source Current (Diode Conduction) <sup>a</sup>	$I_S$	2.3	A
Power Dissipation <sup>a</sup>	$P_D$	3.1	W
		2.2	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150	°C

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Case <sup>a</sup>	$R_{\theta JC}$	25	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	50	°C/W

Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

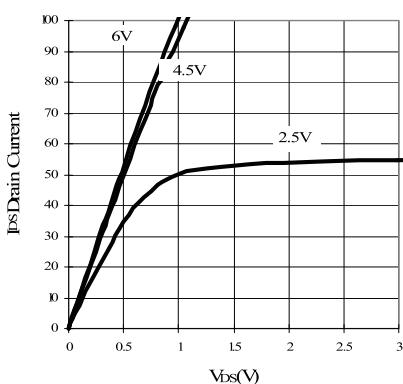
**SPECIFICATIONS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**

Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ	Max	
<b>Static</b>						
Gate-Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	0.6			V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = 12 \text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$		1		uA
		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^\circ\text{C}$		25		
On-State Drain Current <sup>A</sup>	$I_{D(\text{on})}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A
Drain-Source On-Resistance <sup>A</sup>	$r_{DS(\text{on})}$	$V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$		13.5		mΩ
		$V_{GS} = 2.5 \text{ V}, I_D = 8 \text{ A}$		20		
		$V_{GS} = 4.5 \text{ V}, I_D = 15 \text{ A}, T_J = 55^\circ\text{C}$		15		
Forward Transconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_D = 10 \text{ A}$		40		S
Diode Forward Voltage	$V_{SD}$	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$		12.5		nC
Gate-Source Charge	$Q_{gs}$			2.6		
Gate-Drain Charge	$Q_{gd}$			4.6		
<b>Switching</b>						
Turn-On Delay Time	$t_{d(\text{on})}$	$V_{DD} = 25 \text{ V}, R_L = 25 \Omega, I_D = 1 \text{ A}, V_{GEN} = 10 \text{ V}$		20		nS
Rise Time	$t_r$			9		
Turn-Off Delay Time	$t_{d(\text{off})}$			70		
Fall-Time	$t_f$			20		

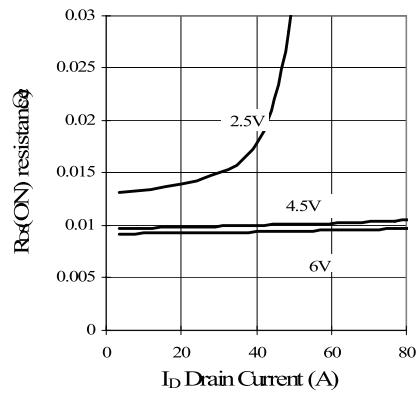
## Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

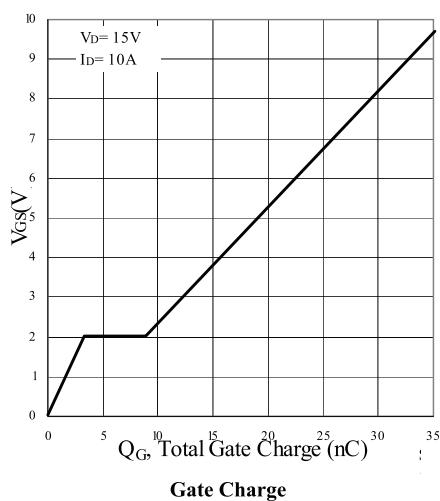
## Typical Electrical Characteristics



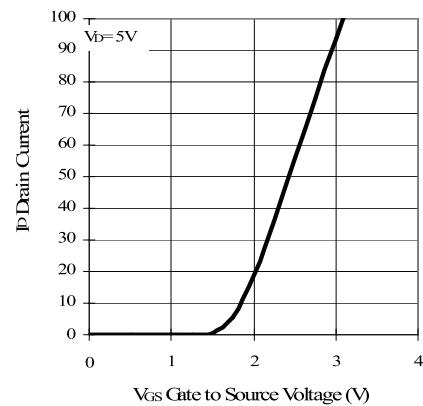
Output Characteristics



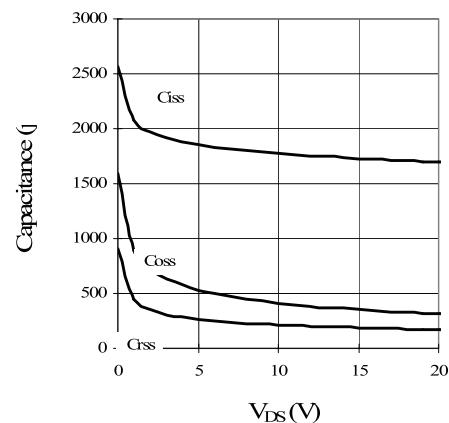
On-Resistance vs. Drain Current



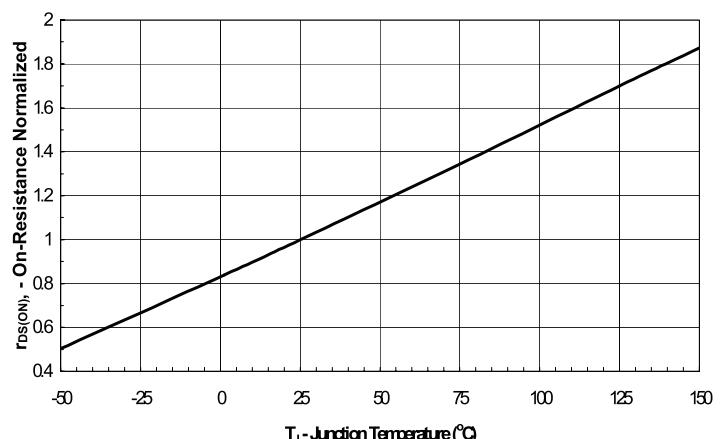
Gate Charge



Transfer Characteristics

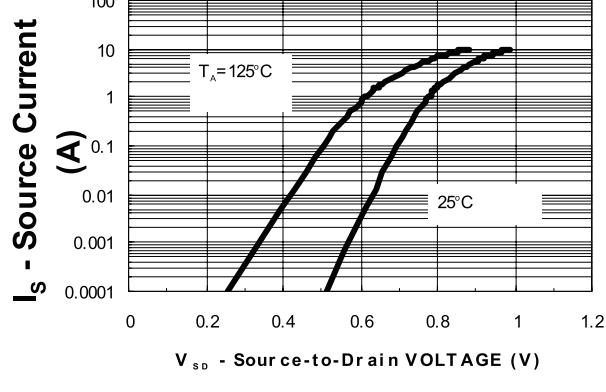


Capacitance

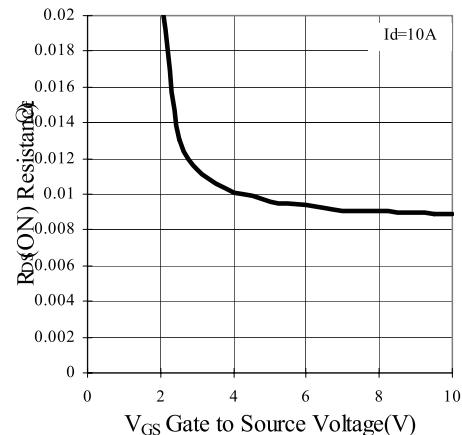


On-Resistance vs. Junction Temperature

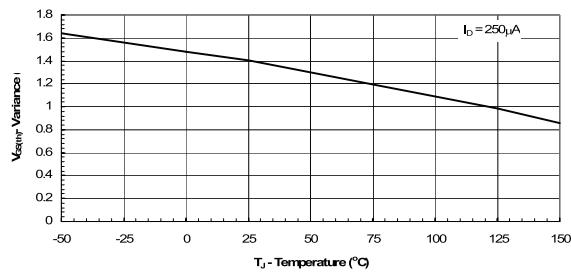
## Typical Electrical Characteristics



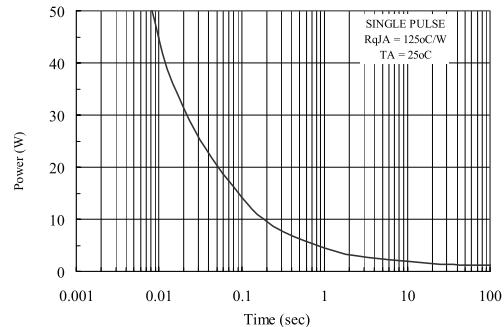
Source-Drain Diode Forward Voltage



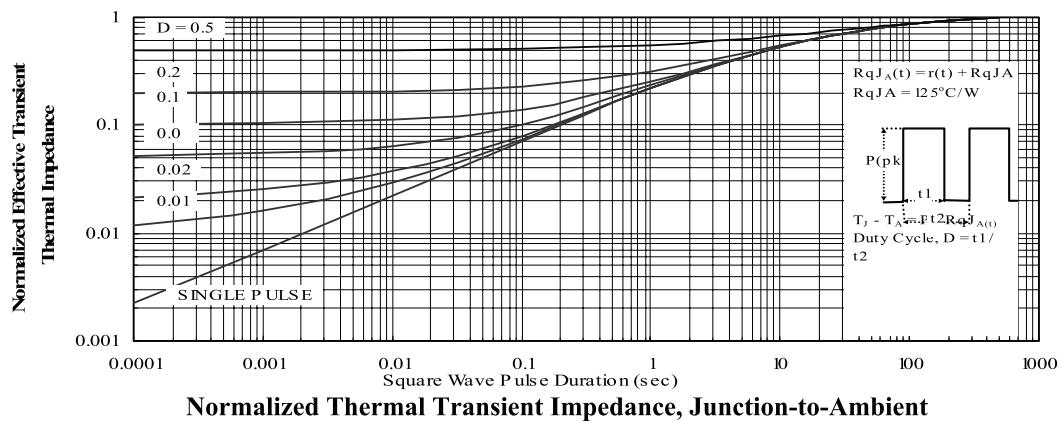
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



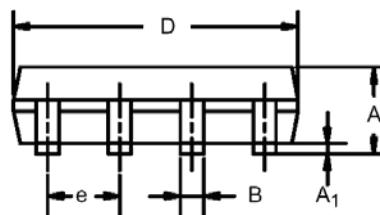
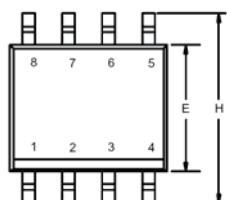
Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient

## Package Information

**SO-8: 8LEAD**



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
<b>A</b>	1.35	1.75	0.053	0.069
<b>A<sub>1</sub></b>	0.10	0.20	0.004	0.008
<b>B</b>	0.35	0.51	0.014	0.020
<b>C</b>	0.19	0.25	0.0075	0.010
<b>D</b>	4.80	5.00	0.189	0.196
<b>E</b>	3.80	4.00	0.150	0.157
<b>e</b>	1.27 BSC		0.050 BSC	
<b>H</b>	5.80	6.20	0.228	0.244
<b>h</b>	0.25	0.50	0.010	0.020
<b>L</b>	0.50	0.93	0.020	0.037
<b>q</b>	0°	8°	0°	8°

